# NSN 5961-01-219-6554

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.219 inches

# **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-111

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

0.438 inches

#### Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage, dc and 60.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

50.0 watts small-signal input power, common-collector absolute

#### **Transfer Ratio:**

150.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: npn

## **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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